

WIS35775

Low Noise 256 Subdivision Microstepping Motor Drive

Product Description

The MS35775 is a high-precision, low-noise, two-phase stepper motor driver. The MS35775 integrates a fast mode and a quiet mode to meet the needs of both high and low speeds.

Different applications. With built-in power MOSFET, the average current can reach 1.4A for long time operation and the peak current is 2A. The chip integrates over-temperature protection, under-voltage protection, over-current protection, short-ground protection, and short-supply protection.



Main features

- 2-phase stepper motors, capable of 2A peak current
- low ON-resistance
- Voltage range 4.75~36V
- STEP/DIR interface, selectable from 2, 4, 8, 16, or 32 microsteps
- Internal 256 breakdown
- Motor stationary automatically enters power saving mode
- Built-in detection resistor mode selectable (external detection resistor no longer required)
- QFN28 package (backside heat sink)

Product Specification Classification

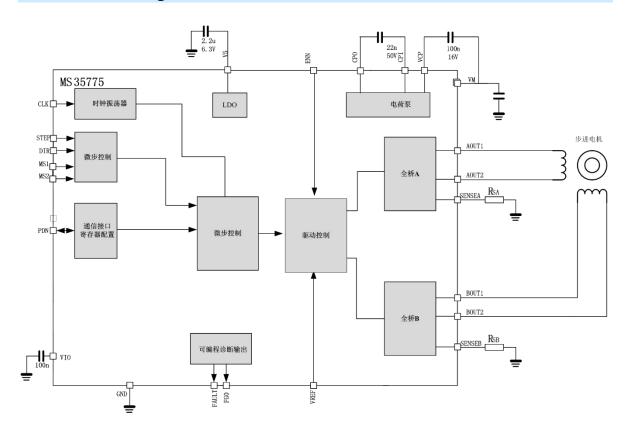
offering	Package form	Screen
S		Printing
		Name
MS35775	QFN28	MS35775

appliance

- Precision industrial equipment
- Medical equipment
- 3D printing
- control

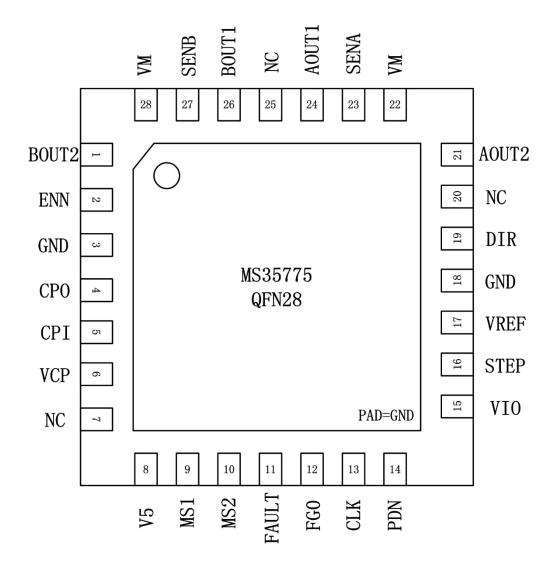


Internal Block Diagram





Pin Arrangement





Pin Descrip	tion		
Pin Number	Pin Name	Pin Attributes	Pin Description
1	BOUT2	Ю	Motor coil B output 2
2	ENN	DI	Enable input pin, turns off output when high
3	GND	GND	structural particle: used before a verb or adjective, linking it preceding the verb or adjective
4	СРО	Ю	Charge Pump Capacitor Output
5	СРІ	Ю	Charge Pump Capacitor Input, 22nF (50V) Capacitor Connected to CPO
6	VCP	Ю	Charge pump voltage with VM connected to 100nF capacitor
7	NC	NC	Pins not in use, can be suspended or grounded
8	V5	Ю	Internal 5V LDO with 2.2uF to 4.7uF capacitor to ground
9	MS1	DI	Micro-step configuration port (built-in pull-down resistor)
10	MS2	DI	Micro-step configuration port (built-in pull-down resistor)
11	FAULT	DO	Internal error signal output. Output driver off when high. Can be reset to high with ENN setting.
12	FG0	DO	Provide A coil positive zero crossing pulse
13	CLK	DI	Clock input. Groundable when using the internal clock
14	PDN	DIO	Power off is not controlled by the input. (Automatic quiescent current attenuation mode at low level)
15	VIO		1.8V to 5V power supply for each digital input and output pin
16	STEP	DI	Microsteps Input Feet
17	VREF	Al	The analog reference voltage controls the current input pin or in the internal sense Analog reference current input in resistive mode
18	GND	GND	structural particle: used before a verb or adjective, linking it preceding the verb or adjective
19	DIR	DI	DIR input pin (built-in pull-down resistor)
20	NC	NC	Pins not in use, can be suspended or grounded
21	AOUT2	10	Motor coil A output 2
22	VM	POWER	Motor supply voltage



23	SENA	Ю	Coil A low side MOS source to sense resistor to ground. Internal sense resistor mode to ground.
24	AOUT1	10	Motor coil A output 1
25	NC	NC	Pins not in use, can be suspended or grounded
26	BOUT1	Ю	Motor coil B output 1
27	SENB	Ю	Coil B low side MOS source to sense resistor to ground. Internal sense resistor mode to ground.
28	VM	POWER	Motor supply voltage



Limit parameters

Absolute maximum rating					
parameters criticize (i.e. enumerate shortcomings)	nota tion		rating		unit (of mea sure)
Supply Voltage	VS	-0.539			V
IO supply voltage	VVIO		-0.55.5		V
Digital supply voltage (using external power supply)	V5VOUT		-0.55.5		V
Logic Input Voltage Range	VI		-0.5 .VIO+0.5		V
VREF Input Voltage (Do not exceed 10% of VIO and V5 at the same time, as this will enter the test mode) style)	VVREF	-0.56			V
Maximum current for analog-digital Scope of workports	IIO	+/-10			mA
parameters criticize (i.e. enumerate shortcomings)	nota	mini F	Parameter r	ange greatest	unit (of
onamorate onorteorningo)	tion	mal	offici al) stan dard		measur e)
Supply voltage range (using internal V5)	vs	mal 5.5	al) stan	36	
Supply voltage range (using internal			al) stan	36 5.4	e)
Supply voltage range (using internal V5) Supply voltage range (VS and V5	VS	5.5	al) stan		e) V
Supply voltage range (using internal V5) Supply voltage range (VS and V5 together)	VS VS	5.5	al) stan	5.4	e) v
Supply voltage range (using internal V5) Supply voltage range (VS and V5 together) I/O supply voltage range	VS VS VVIO	5.5	al) stan	5.4	e) V
Supply voltage range (using internal V5) Supply voltage range (VS and V5 together) I/O supply voltage range RMS Current per Motor Coil One second on, one second off. RMS	VS VS VVIO IRMS	5.5	al) stan	5.4 5.25 1.2	e) V V A



Electrical parameters

VM=24V

Note: Not specified, ambient temperature is $Ta = 25^{\circ}C \pm 2^{\circ}C$. **Current Power Consumption:**

notati	Test Conditions	minimum	typical	maxim	unit
on		value	value	um	(of
				values	mea
					sure)
IS	F-II. 4204II- ma		10	1.4	mA
			10	14	l IIIA
	chopping				
IS	Fclk = 12MHz, 35kHz		11		mA
	chopping		11		IIIA
	waviness				
IVCC	Fclk = 12MHz, 35kHz		10		A
	chopping		10		mA
	waviness				
IVIO	10 without any load		30		uA
	on IS	Fclk = 12MHz. no chopping Fclk = 12MHz, 35kHz chopping waviness Fclk = 12MHz, 35kHz chopping waviness	on value Fclk = 12MHz. no chopping Fclk = 12MHz, 35kHz chopping waviness Fclk = 12MHz, 35kHz chopping waviness	on value value Fclk = 12MHz. no chopping Fclk = 12MHz, 35kHz chopping waviness Fclk = 12MHz, 35kHz chopping waviness Fclk = 12MHz, 35kHz chopping waviness	on value value um values Fclk = 12MHz. no chopping Fclk = 12MHz, 35kHz chopping waviness Fclk = 12MHz, 35kHz chopping waviness 10 Fclk = 12MHz, 35kHz chopping waviness

Digital inputs and outputs:

Pigitat inpats a	na outputs					
parameters	notati	Test Conditions	minimu	typical	maximu	unit
criticize (i.e.	on		m value	value	m	(of
enumerate					values	mea
shortcomings)						sure)
Input low potential	VINLO		-0.3		0.3Vio	V
Input high	VINHI		0.7Vio		Vio+0.3	V
potential						
Input SMIT	VINHYST			0.12Vio		V
hysteresis						
Output high	VOUTLO	I=2mA	Vio-0.2			V
potential						
Motor Drive:	VOUTHI	I=2mA			0.2	V
parameters	notatio	Test Conditions	minimu	typical	maximu	unit
criticize (i.e.	n		m value	value	m	(of
enumerate					values	mea
shortcomings)						sure)
Down Resistors Low end rason	RONL	I=100mA		0.28	0.38	Ω
Digital Port High-end rdson	RONH	I=100mA		0.29	0.39	pF Ω
Capacitance rising time	tSLPON	I=700mA	40	80	160	ns
descent time	tSLPOFF	I=700mA	40	80	160	ns
Charge Rhane:	IOIDLE					
parameters	notatio	Test Conditions	minimu	typical	maximu	unit
criticize (i.e.	n		m value	value	m	(of
enumerate					values	mea
shortcomings)	i.com				r ayes/	sure)
Charge_pump	VVCP-VS	Operates at fchop <	4	Vcc-0.3	VSC Page	V
Output		40kHz			i age	



5V	LDO:

5V LDO:	1		I	1	I	
parameters	notatio	Test Conditions	minimu	typical	maximu	unit
criticize (i.e.	n		m value	value	m	(of
enumerate					values	meas
shortcomings)						ure)
output voltage	V5	I5v=0mA	4.8	5	5.2	V
output resistance	RV5	static load		1		Ω
Deviation within	V5T (DEV)	I=5mA, full operating temperature		±90	±200	mV
Clockoscolfato	 :	range				
parameters	notati	Test Conditions	minimu	typical	maximu	unit
criticize (i.e.	on		m value	value	m	(of
enumerate					values	mea
shortcomings)						sure)
95	fCLKOSC	T=50°C		11.7		MHz
Clockrange	fCLKOSC	T=25°C	11.5	12.0	12.5	MHz
frequency	fCLKOSC	T=150°C		12.1		MHz
(factory	TELKOSE			12.1		141112
setting)						
applied clock	fCLK		4	10-16	18	MHz
Detecting signa	ılc•					
	notatio	Test Conditions	minimu	tunical	maximu	unit
parameters		Test Conditions		typical value		unit
criticize (i.e.	n		m value	value	m values	(of
enumerate					values	mea
shortcomings)		Cumply Voltage Dice	2.5	4.2	1.5	sure)
Eximalentochage	VUV VS Xtimeout	Supply Voltage Rise	3.5 32	4.3	4.6 48	Fcl k ∕
protestiont		5VIDO Valtara Dias		4.2		cycl
V5 Undervoltage	VUV_V5	5V LDO Voltage Rise		4.2		eγ
protection						
Upper tube	VOS2G		2	2.5	3	V
overcurr						
ent						
protectio						
n voltage						
Lower tube	VOS2VS		1.6	2	2.2	.,
overcurr	V032V3		1.6	2	2.3	V
ent						
protectio						
n voltage						
Upper and	tS2G	High end output level	0.8	1	2	us
lower tube		to VSP-3V				
short circuit		10 751 57				
protection						
detection						
time					2020 0 22	
Hangzhou Ruime overtemperature Technology Co. warning	ng _{tOTPW}	rise of temperature	100	120	2020.9.30 140 Total 15	°C
http://www.felmo Over-	n.com				Pages8	
	tOT143	rise of temperature	128	143	1 Ra ge	°C
temperature		·				



Sense resistor voltage:

Sense resistor v	oltage:					
parameters	notati	Test	minimum	typical	maximum	unit
criticize (i.e.	on	Conditions	value	value	values	(of
enumerate						meas
shortcomings						ure)
)						
Sense Voltage						
Peak Voltage	VSRTL			300		mV
(Low						
Sensitivity)						
(degrees)						
Sense Voltage						
Peak Voltage	VSRTH			165		mV
(High						
Sensitivity)						
(degrees)						
Internal Brx to						
external sense	Rxy			30		mΩ
internal	,					
resistance						
between						



Functional Description

The MS35775 is a two-phase stepper motor driver that utilizes a full-bridge output structure consisting of dual NDMOS to provide high current drive capability.

ENN controls the output driver, turning it on when ENN is low.

The MS35775 peripheral control is simple and its quiet nature is

particularly suitable for home or office use. Microstep control

The microstep steps are controlled by MS1 and MS2 as shown in the table below. a 160kΩ pull-down

MS2 resistor is built into the MSx.	MS1	step by step
0	0	1/8
0	1	1/2
1	0	1/4
1	1	1/16

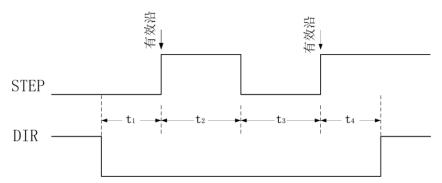
STEP Input

Each STEP can be a full step and a microstep. A full step can be equal to 2,4,8,16,32,64,128,256 microsteps. The internal tables are converted to sine and cosine values to control the motor current.

The MS35775 also incorporates an internal STEP pulse generator for applications that do not require precise position but only precise time and speed.

Direction control DIR

The direction of motor operation can be controlled by the DIR pin. The following diagram shows the timing of the STEP and DIR controls.



parameters	notat	prerequisite	mini	typic	greates	unit
	ion		mal	al	τ	(of
				case		mea
						sure)
STEP Frequency	fSTEP				1/2 _{fCLK}	
full step frequency	fFS				fCLK/51	
DIR to STEP setup time	t1		20			ns
STEP Minimum High Level	t2			100		ns



Time						
STEP Minimum Low Level Time	t3			100		ns
DIR to STEP hold time	t4		20			ns
STEP and DIR Burr Filter Time	t5	Rising or falling edge	13	20	30	ns



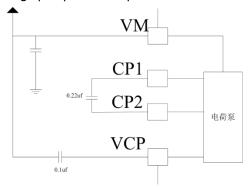
5V Regulated Power Supply

The MS35775 also provides a 5V regulated power output, which requires a capacitor between 2.2uF and 4.7uF. There is an internal structure to detect the V5 voltage, and all output tubes will shut down if there is an abnormality (low voltage).

charge pump

Since the output stage utilizes an N-channel FET, a gate voltage higher than the supply voltage is required to drive the tube fully open. The MS35775 has an internal charge pump circuit to generate this high voltage.

For normal operation, the charge pump circuit requires two external capacitors, as shown below:



current control

The peak current of motor operation is determined by the combination of the R_{SENSE} resistance and the input voltage at the VREF pin.

The formula for calculating the peak current is as follows:

$$I_{RMS} = \frac{300mV}{RSENSE} * \frac{VVREF}{2.5V}$$

The corresponding RMS current is calculated as follows:

$$I_{RMS} = \frac{300mV}{RSENSE} * \frac{1}{\sqrt{2}} * \frac{v_{VREF}}{2.5V}$$

Automatic current attenuation

The automatic current attenuation feature is enabled by pulling down the PDN pin, which reduces power consumption to 33% when running at about 50% current.

Over Zero Output Flag

The MS35775 provides the over-zero output flag bit FG0, which outputs a pulse signal when the motor coil current is positively over-zero. **Error Output Flag**

When an internal error signal occurs, a diagnostic signal is output through the error indication pin FAULT pin.

The ENN pin is reset and FAULT is low

during normal operation.

Protection Circuit

The MS35775 features over-current protection, under-voltage protection, and over-temperature



protection.

When the motor loads are shorted together or directly grounded, the chip will protect itself by detecting the overcurrent and shutting down the shorted driver tubes, stopping damage to the internal devices, and FAULT outputs a high signal that requires the ENN pin to be reset.

When the temperature of the chip exceeds the set threshold, the over-temperature protection circuit will function and all channels will be shut down and FAULT output.

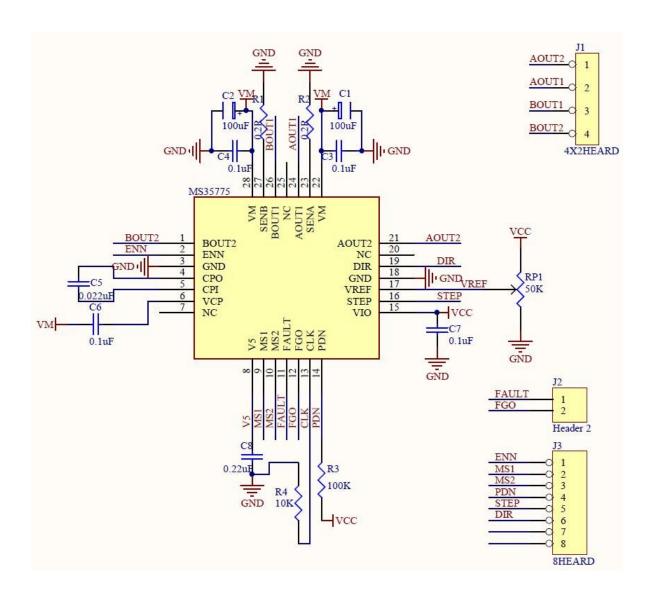


A high signal. When the temperature falls back to a safe temperature, the chip will return to normal operation.

When the chip's supply voltage drops below the undervoltage protection threshold, the chip shuts down all channels and resets the internal logic circuits. When the voltage returns above the threshold, the chip returns to normal operation.

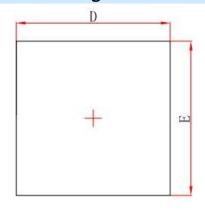


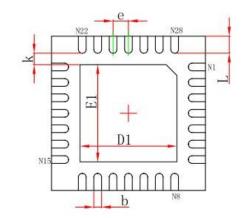
Typical Application Diagram





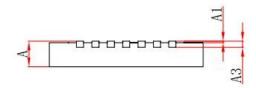
Package Outline Diagram





Top View

Bottom View



Side View

Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	0.700/0.800	0.800/0.900	0.028/0.031	0.031/0.035	
A1	0.000	0.050	0.000	0.002	
A3		0.203REF.	0.008REF.		
D	4.900	5.100	0.193	0.201	
E	4.900	5.100	0.193	0.201	
D1	3.050	3.250	0.120	0.128	
E1	3.050	3.250	0.120	0.128	
k	0.200MIN.		0.008MIN.		
b	0.180	0.300	0.007	0.012	
е	0.500 TYP.		0.020TYP.		
L	0.450	0.650	0.018	0.026	



Seal and Packaging Code

I. Introduction to the content of the seal



Model No: MS35775

Production lot number: XXXXXXXX

II. Requirements for the specification of seals
It is laser printed, centered and in Arial font.

III. Packaging instructions:

model	Package	only/roll	Rolls/box	Only/box	Box/Cart	Only/bo
number	form				on	x
MS35775	QFN28	1000	8	8000	4	32000

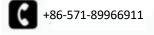




Precautions for MOS circuit operation:

Static electricity is generated in many places. Taking the following precautions can effectively prevent damage to MOS circuits due to the effects of electrostatic discharge:

- 1. The operator should be grounded through an anti-static wrist strap.
- 2. The equipment enclosure must be grounded.
- 3. Tools used in the assembly process must be grounded.
- 4. It must be packed or transported in conductor packaging or antistatic materials.







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